



Agilent HCPL-314J

0.4 Amp Gate Drive Optocouplers

Reliability Data Sheet

Description

The reliability data shown includes Agilent Technologies reliability test data from the qualification of this product family. All of these products use the same LEDs, similar IC, and the same packaging materials, processes, stress conditions and testing. The data in Table 1 and Table 2 reflect actual test data for devices on a per channel basis. Before stress, all devices are preconditioned using a solder reflow process (260°C, 5 sec. 2X) and 20 temperature cycles (-55°C to +125°C, 15 minutes dwell, 5 minutes transfer). These data are taken from testing on

Agilent Technologies devices using internal Agilent process, material specifications, design standards, and statistical process controls. **THEY ARE NOT TRANSFERABLE TO OTHER MANUFACTURERS' SIMILAR PART TYPES.**

Operating Life Test

For valid system reliability calculations it is necessary to adjust for the time when the system is not in operation. Note that if you are using MIL-HDBK-217 for predicting component reliability, the results may not be comparable to

those given in Table 2 due to different conditions and factors that have been accounted for in MIL-HDBK-217. For example, it is unlikely that your application will exercise all available channels at full rated power with the LED(s) always ON as Agilent Technologies testing does. Thus, your application total power and duty cycle must be carefully considered when comparing Table 2 to predictions using MIL-HDBK-217.

Table 1. Demonstrated Operating Life Test Performance

Stress Test Condition	Total Devices Tested	Total Device Hours	Number of Failed Units	Demonstrated MTTF (hr) @ $T_A = +100^\circ\text{C}$	Demonstrated FITs @ $T_A = +100^\circ\text{C}$
$T_A = +100^\circ\text{C}$ $V_{CC1} = 35.0\text{ V}$ $V_{in} = 11.5\text{ V}$	285	285,000	0	> 285,000	< 3,509

Definition of Failure

Inability to switch, i.e., “functional failure”, is the definition of failure in this data sheet. Specifically, failure occurs when the device fails to switch ON with 2 times the minimum recommended drive current (but not exceeding the max. rating) or fails to switch OFF when there is no input current.

Failure Rate Projections

The demonstrated point mean time to failure (MTTF) is measured at the absolute maximum stress condition. The failure rate projections in Table 2 use the Arrhenius acceleration relationship, where a 0.43eV activation energy is used as in the hybrid section of MIL-HDBK-217.

Application Information

The data of Tables 1 and 2 were obtained on devices with high temperature operating life duration up to 1000 hours. An exponential (random) failure distribution is assumed, expressed in units of FIT (failures per billion device hours) are only defined in the random failure portion of the reliability curve.



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Table 2. Reliability Projections (per channel) for Devices Listed in Title

Ambient Temperature (°C)	Junction Temperature (°C)	Typical (60% Confidence)		90% Confidence	
		MTTF (hr/fail)	FITs (fail/10 ⁹ hr)	MTTF (hr/fail)	FITs (fail/10 ⁹ hr)
100	115	311,000	3,215	123,000	8,079
90	105	437,000	2,289	174,000	5,752
80	95	625,000	1,600	249,000	4,020
70	85	912,000	1,096	363,000	2,754
60	75	1,361,000	735	541,000	1,846
50	65	2,079,000	481	827,000	1,209
40	55	3,258,000	307	1,297,000	771
30	45	5,254,000	190	2,091,000	478
25	40	6,748,000	148	2,685,000	372

Table 3. Mechanical Tests (Testing done on a constructional basis)

Test Name	MIL-STD-883	Test Conditions	Units Tested	Units Failed
Temperature Cycle	1010 Cond. B	-55 to 125°C Transfer = 5 mins Dwell = 15 mins 1000 cycles	120	0
Solderability	2003	Sn60 Pb40 Solder Temp. = 230°C (2 sec.)	20	0

Table 4. Environmental Testing

Test Name	MIL-STD-883	Test Conditions	Units Tested	Units Failed
Temp. and Humidity Bias	N/A	T _A = 85°C, RH = 85% See Table 1 for bias condition. Time = 1000 hours	120	0
Unbiased Pressure Pot	N/A	T _A = 121°C, RH = 100% Unbiased Time = 168 hours	100	0
Resistance to Solvents	2015	3 one-min. immersion Brush after solvent	80	0

Table 5. Basic Material Properties

Material Property	Test Result
Mold Compound Flammability Classification	UL 94V-0
Mold Compound Oxygen Index	32%
Mold Compound Glass Transition Temperature	T _g = 165°C
Mold Compound Hydrolyzable Chlorine	< 15 ppm

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Data subject to change.

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September 25, 2001

5988-4130EN



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